



Product Summary

BV _{DSS}	Rds(on) Max	I _D Max T₄ = +25°C
	110mΩ @ V _{GS} = -10V	-4.2A
-60V	130mΩ @ V _{GS} = -4.5V	-3.9A

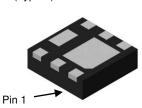
Description and Applications

This MOSFET is designed to minimize the on-state resistance (RDS(ON)), yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

U-DFN2020-6 (Type F)

- **Battery Management Application**
- **Power Management Functions**
- **DC-DC Converters**





Top View

Bottom View

Features and Benefits

- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Notes 3)
- For automotive applications requiring specific change control (i.e.: parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please refer to the related automotive grade (Q-suffix) part. A listing can be found at

P-CHANNEL ENHANCEMENT MODE MOSFET

https://www.diodes.com/products/automotive/automotiveproducts/.

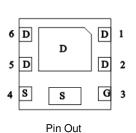
This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability.

https://www.diodes.com/quality/product-definitions/

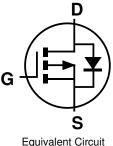
An Automotive-Compliant Part is Available Under Separate Datasheet (DMP6110SFDFQ)

Mechanical Data

- Case: U-DFN2020-6
- Case Material: Molded Plastic, "Green" Molding Compound. • UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish NiPdAu over Copper Leadframe. Solderable per MIL-STD-202, Method 208(e3)
- Weight: 0.007 grams (Approximate)



Bottom View



Ordering Information (Note 4)

Part Number	Case	Packaging
DMP6110SFDF-7	U-DFN2020-6 (Type F)	3,000/Tape & Reel
DMP6110SFDF-13	U-DFN2020-6 (Type F)	10,000/Tape & Reel

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. Notes:

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



Marking Information

Site 1:



 $\begin{array}{l} P0 = Product Type Marking Code \\ YM = Date Code Marking \\ Y = Year (ex: H = 2020) \\ M = Month (ex: 9 = September) \end{array}$

Year	2015		2020	2021	2022	2023	2024	2025	2026	2027	2028	2029
Code	С		Н		J	K	L	М	Ν	0	Р	R
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec

Site 2:



P0 = Product Type Marking Code YWX = Date Code Marking Y = Year (ex: 0 = 2020) W = Week (ex: a = week 27; z represents week 52 and 53) X = Internal Code (ex: U = Monday)

Date Code Key

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Year	2015		2020	2021	2022	2023	2024	2025	2026	2027	2028	2029
Code	5		0	1	2	3	4	5	6	7	8	9
Week	1-26			27-52				53				
Code		A-Z			A-Z a-z				Z			
Internal Code	Sun	1	Mon		Tue	W	ed	Thu		Fri		Sat
Code	Т		U		V	V	V	Х		Y		Ζ



Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage		VDSS	-60	V	
Gate-Source Voltage			V _{GSS}	±20	V
Continuous Drain Current (Note C) V 10V	Steady State	T _A = +25°C T _A = +70°C	D	-3.5 -2.8	А
Continuous Drain Current (Note 6) $V_{GS} = -10V$	t<10s	T _A = +25°C T _A = +70°C	ID	-4.2 -3.4	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)		IDM	-20	А	
Continuous Source-Drain Diode Current (Note 6)	TA = +25°C	ls	-2.1	А	
Avalanche Current (Note 7) L = 0.1mH	las	-19	А		
Avalanche Energy (Note 7) L = 0.1mH			Eas	18	mJ

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Total Bower Dissipation (Note 5)	TA = +25°C	D-	0.76	W	
Total Power Dissipation (Note 5)	TA = +70°C	PD	0.47		
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	ReJA	167	°C/W	
Thermal Resistance, Junction to Ambient (Note 5)	t<10s	ΠθJA	121		
Total Power Dissipation (Note 6)	$T_A = +25^{\circ}C$	Pp	1.97	W	
Total Fower Dissipation (Note 0)	$T_A = +70^{\circ}C$	PD	1.30	vv	
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	Steady State			
Thermal Resistance, Junction to Ambient (Note 0)	t<10s	Reja	42	°C/W	
Thermal Resistance, Junction to Case (Note 6)	Steady State	Rejc	8		
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C	

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Turn	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 8)	Symbol	IVIIII	Тур	Wax	Unit	Test Condition
Drain-Source Breakdown Voltage	D)/	-60		_	V	
	BVDSS				-	$V_{GS} = 0V, I_D = -250\mu A$
Zero Gate Voltage Drain Current $T_J = +25^{\circ}C$	IDSS	—		-1	μΑ	$V_{DS} = -48V, V_{GS} = 0V$
Gate-Source Leakage	lgss	—	—	±100	nA	$V_{GS} = \pm 16V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 8)		1	1	1		
Gate Threshold Voltage	Vgs(th)	-1	—	-3	V	$V_{DS} = V_{GS}$, $I_D = -250 \mu A$
Static Drain-Source On-Resistance	Descent		—	110	mΩ	$V_{GS} = -10V, I_D = -4.5A$
	RDS(ON)	_	—	130	11122	$V_{GS} = -4.5V, I_D = -3.5A$
Diode Forward Voltage	Vsd	_	-0.7	-1.2	V	VGS = 0V, IS = -1A
DYNAMIC CHARACTERISTICS (Note 9)						
Input Capacitance	Ciss	—	969	—		
Output Capacitance	Coss	—	58	—	pF	V _{DS} = -30V, V _{GS} = 0V, f = 1.0MHz
Reverse Transfer Capacitance	Crss	—	44	—		
Gate Resistance	Rg	_	14	_	Ω	V _{DS} = 0V, V _{GS} = 0V, f = 1.0MHz
Total Gate Charge (V _{GS} = -4.5V)	Q _G	—	8.2	_		
Total Gate Charge (V _{GS} = -10V)	QG	_	17.2	_	-0	
Gate-Source Charge	QGS	_	3.0	_	nC	$V_{DS} = -30V, I_{D} = -12A$
Gate-Drain Charge	Qgd	—	3.1	—		
Turn-On Delay Time	td(on)	_	4.4	_		
Turn-On Rise Time	t _R	—	23			$V_{GS} = -10V, V_{DS} = -30V, R_{GEN} =$
Turn-Off Delay Time	tD(OFF)	—	34	_	ns	6Ω, I _D = -12A
Turn-Off Fall Time	tF	—	42	—		
Reverse Recovery Time	t _{RR}	_	13.2	_	ns	I _S = -12A, di/dt = -100A/µs
Reverse Recovery Charge	QRR	_	6.2	_	nC	Is = -12A, di/dt = -100A/µs

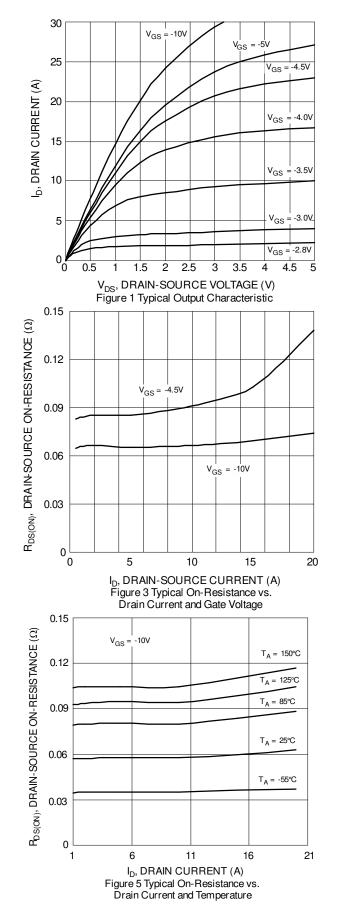
 Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
Device mounted on FR-4 substrate PC board, 2oz copper, with 1-inch square copper plate. Notes:

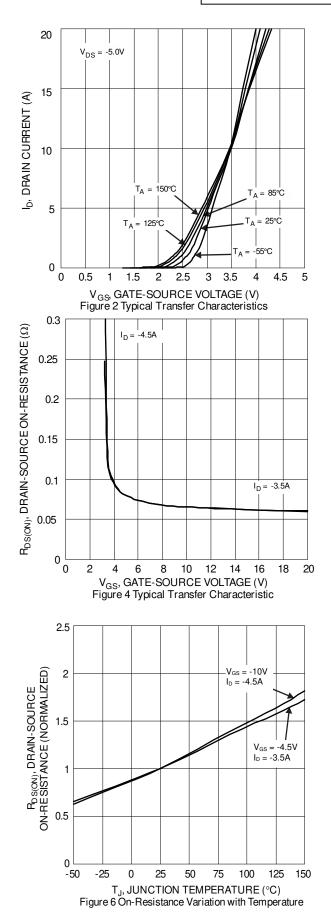
7. I_{AS} and E_{AS} ratings are based on low frequency and duty cycles to keep $T_J = +25^{\circ}C$.

8. Short duration pulse test used to minimize self-heating effect.

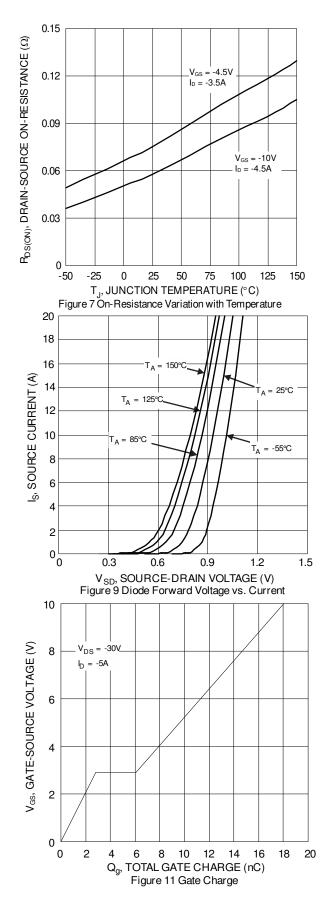
9. Guaranteed by design. Not subject to product testing.

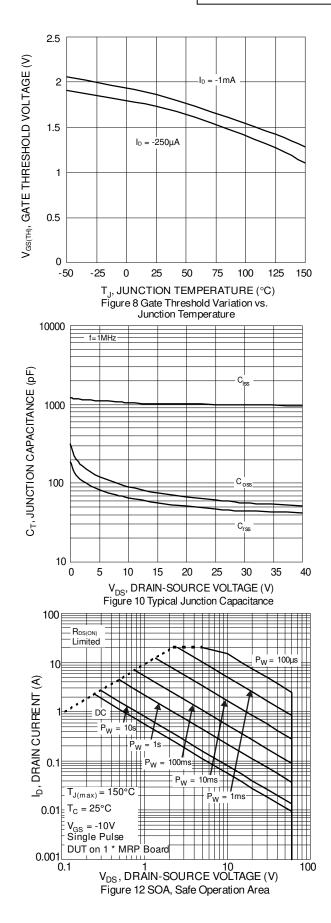




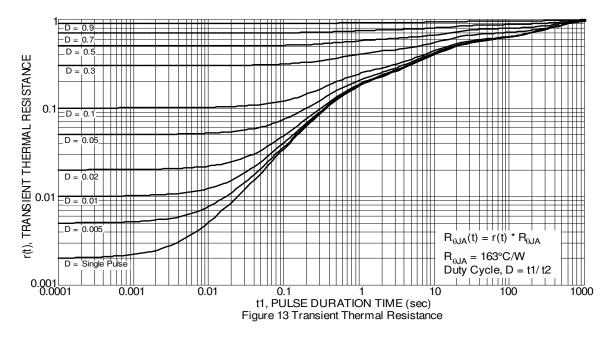








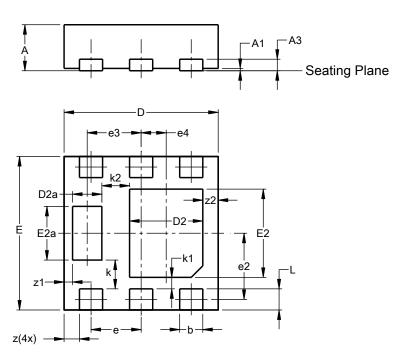






Package Outline Dimension

Please see http://www.diodes.com/package-outlines.html for the latest version.

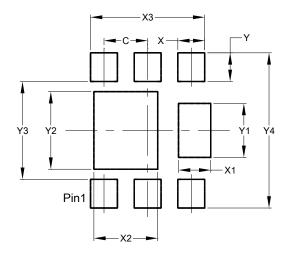


	-	12020-6 be F)					
Dim	Min	Max	Тур				
Α	0.57	0.57 0.63 0.60					
A1	0.00 0.05 0.03						
A3	-	-	0.15				
b	0.25	0.35	0.30				
D	1.95	2.05	2.00				
D2	0.85	1.05	0.95				
D2a	0.33	0.43	0.38				
E	1.95	2.05	2.00				
E2	1.05	1.25	1.15				
E2a	0.65	0.75	0.70				
е		0.65 BS	С				
e2	0).863 BS	SC				
e3		0.70 BS	С				
e4	0).325 BS	SC				
k		0.37 BS	С				
k1		0.15 BS	-				
k2		0.36 BS					
L		0.325					
z		0.20 BS	-				
z1	0).110 BS	SC				
z2		0.20 BS	С				
All C	Dimens	ions in	mm				

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

U-DFN2020-6 (Type F)



Dimensions	Value (in mm)
С	0.650
Х	0.400
X1	0.480
X2	0.950
X3	1.700
Y	0.425
Y1	0.800
Y2	1.150
Y3	1.450
Y4	2.300

U-DFN2020-6 (Type F)



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